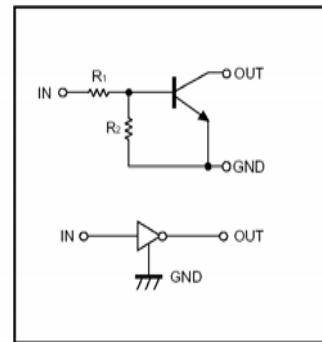


DIGITAL TRANSISTOR (NPN)

Features

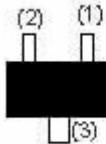
1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
3. Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



PIN CONNECTIONS AND MARKING

DTC124EE

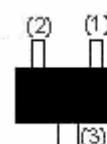


1.IN
2.GND
3.OUT

SOT-523

Addreviated symbol: 25

DTC124EUA

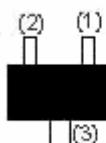


1.IN
2.GND
3.OUT

SOT-323

Addreviated symbol: 25

DTC124EKA

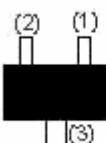


1.IN
2.GND
3.OUT

SOT-23-3L

Addreviated symbol: 25

DTC124ECA

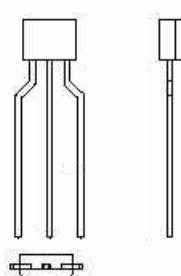


1.IN
2.GND
3.OUT

SOT-23

Addreviated symbol: 25

DTC124ESA



1.GND
2.OUT
3.IN

TO-92S

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTC124E)					Unit
		E	UA	KA	CA	SA	
Supply voltage	V _{CC}			50			V
Input voltage	V _{IN}			-10~40			V
Output current	I _O			30			mA
	I _{C(MAX)}			100			
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _j			150			°C
Storage temperature	T _{stg}			-55~150			°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			0.5	V	V _{CC} =5V, I _O =100μA
	V _{I(on)}	3				V _O =0.2V, I _O =5 mA
Output voltage	V _{O(on)}		0.1	0.3	V	I _O /I _I =10mA/0.5mA
Input current	I _I			0.36	mA	V _I =5V
Output current	I _{O(off)}			0.5	μA	V _{CC} =50V, V _I =0
DC current gain	G _I	56				V _O =5V, I _O =5mA
Input resistance	R _I	15.4	22	28.6	KΩ	
Resistance ratio	R ₂ /R ₁	0.8	1	1.2		
Transition frequency	f _T		250		MHz	V _O =10V, I _O =5mA, f=100MHz

Typical Characteristics
●Electrical characteristic curves
